Tantalum capacitors

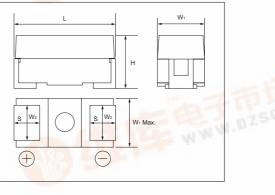
Chip tantalum capacitors with open-function built-in

TCFG series

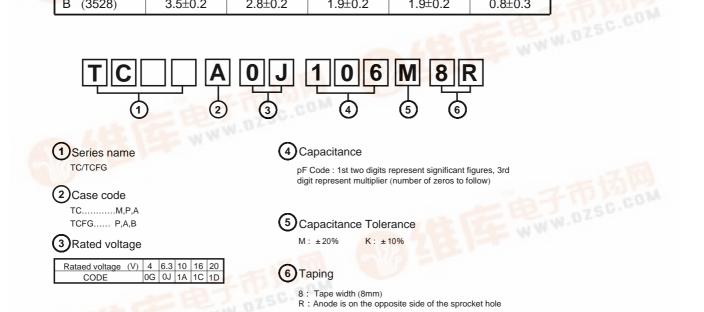
Features

- 1) Safety design by open functiom built in. DZSC.COM
- 2) Wide capacitance range
- 3) Screening by thermal shock.

External dimensions (Units : mm)



Case code	- E 2	W1	W2	Н	S
P (2012)	<mark>2.0</mark> ±0.2	1.25±0.2	0.9±0.2	Max.1.20	0.45±0.3
A (3216)	3.2±0.2	1.6±0.2	1.2±0.2	1.6±0.2	0.8±0.3
B (3528)	3.5±0.2	2.8±0.2	1.9±0.2	1.9±0.2	0.8±0.3





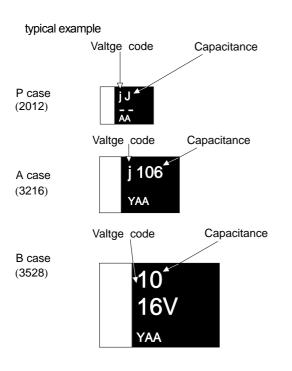
Tantalum capacitors

•Capacitance range

TCFG series

		Raited	voltage	(V.DC)	
μF	4 0G	6.3 0J	10 1A	16 1C	20 1D
1.0			Р	P,A	А
1.5		Р	P,A	А	
2.2	Р	Р	P,A	А	
3.3	Р	P,A	P,A	A,B	
4.7	P,A	P,A	P,A,B	A,B	
6.8	P,A	P,A	A,B	A,B	
10	P,A	P,A,B	A,B	A,B	
15	P,A,B	P,A,B	A,B	В	
22	P,A,B	A,B	A [*] ,B	В	
33	A,B	A,B	В		
47	A,B	В	В		
68	В	В			
100	В	В			

*Please contact us about this product.



Tantalum capacitors

Characteristics

Ite	m		Performance			erformance			Test methods / conditions (based on JIS C 5102, 5143)	
Operating temperature		–55°C ~ +125°C								
Max. operating temperature at rated voltage		+8	5°C							
Rated voltage (V. DC)	4	6.3 1	0 16	6 2	0				
Derated voltage	e (V. DC)	2.5	4 6	3 10) 1	3		at	t 12	5°C
Surge voltage (V. DC)	5.2	8 1	3 20) 2	6				
Leakage currer	nt	0.0		Deta	ails a	are	o the larger of 0.5μA or given in Table 1, ist".			sured value 60s after application ed voltage.
Capacitance ra	nge	1.0) ~ 10)μF				M M	leas	sured frequency: $120 \pm 12Hz$ sured voltage: 0.5Vrms + 1.5V. DC sured circuit: equivalent series it
tanδ	P case		F to 4 βμF to				max. max.	M	leas	sured frequency: $120 \pm 12Hz$ sured voltage: 0.5Vrms + 1.5V. DC sured circuit: equivalent series
	A case	1μF max.: 0.04 max. 1.5μF to 22μF : 0.06 max. 33μF to 47μF : 0.08 max.				rcui				
	B case						max. 3 max.			
Impedance	P case	27.	27.5Ω max.						sured frequency: 100 ± 10 Hz	
	A case	20.0Ω max.								sured voltage: 0.5Vrms max. sured circuit: equivalent series
	B case	15.	.0Ω m	ax.				circuit		
Resistance to solder heat	Appearance						larities, and the asy to read.	Direct immersion into solder bath Solder bath temperature: 260 ± 5°C Immersion time: 5s Immersion cycles: 1 time		
	L.C	Mu	ist sat	isfy t	he i	niti	al specified value.			
	ΔC / C	A \cdot B case within ± 5% P case within ± 10%								
	tanδ						ess or initial specified tolerance. fy the initial specified value.			
Open function operation		320	0°C fo	r 20s	s or	les	5			t immersion into solder bath $\pm 5^{\circ}$ C)
Temperature cycle	Appearance						larities, and the asy to read.			our cycles in the table below are ated five times in succession.
	L.C						al specified value. % of initial limit.		1	$\begin{tabular}{c} Temperature & Time \\ -55 \pm 3^{\circ}C & 30 \pm 3mins. \end{tabular}$
	ΔC / C		ase v B ca						2 3	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
	tanδ						ess or initial specified tolerance. fy the initial specified value.		4	Room temperature 3mins. max.
Resistance to humidity Appearance No noticeable irregularities, and the markings must be easy to read.			Measured after being left for 500 \pm 12hrs. at 60 \pm 2°C and 90 to 95%							
(steady state)	L.C	Mu	ist sat	sfy t	he i	niti	al specified value.	RH, then 1 to 2 hrs. at normal room temperature and humidity.		
	ΔC/C		case v B cas						p	
	tanδ						ess or initial specified tolerance. fy the initial specified value.			

Tantalum capacitors

Iter	m	Performance	Test methods / conditions (based on JIS C 5102,5143)		
Temperature	Temperature	–55°C			
characteristics $\Delta C / C$	ΔC / C	P case within +0% and -15% of the value before testing. A \cdot B case within +10% and -0% of the value before testing.			
	tanδ	P case within 1.5 times of the value before testing. A • B case must satisfy the initial specified value.			
	L.C	_			
	Temperature	+85°C			
	ΔC / C	P case within +0% and -15% of the value before testing. A \cdot B case within +0% and -10% of the value before testing.			
	tanδ	Must satisfy the initial specified value.			
	L.C	Less than or equal to the larger of $5\mu A$ or 0.1CV.			
	Temperature	+125°C			
	ΔC / C	P case within +20% and -0% of the value before testing. A \cdot B case within +15% and -0% of the value before testing.			
	tanδ	P case within 1.5 times of the value before testing. A • B case must satisfy the initial specified value.			
	L.C	Less than or equal to the larger of 6.3µA or 0.125CV.			
Surge resistance	Appearance	A · B case no noticeable irregularities, and the markings must be easy to read.	Apply the rated surge voltage for $30 \pm 5s$ at intervals of $5 \pm .05mins$.		
	L.C	Must satisfy the initial specified value.	1000 times, with the temperature at $85 \pm 2^{\circ}$ C.		
	ΔC / C	P case within ± 10% A • B case within ± 5%			
	tanδ	P case within 1.5 times of the value before testing. A \cdot B case must satisfy the initial specified value.			
High- temperature	Appearance	No noticeable irregularities, and the markings must be easy to read.	Temp. : $85 \pm 2^{\circ}$ C Series Resistance : 3Ω max.		
load	L. C	Must satisfy the initial specified value.	Applied voltage : rated voltage Test time : P case 1000 - 8 hrs		
	ΔC / C	Within ± 10%	A - B case 2000 ⁺⁷³ / ₋₀ hr		
	tanδ	P case within 1.5 times of the value before testing. A • B case must satisfy the initial specified value.	meusure made after pieces shall be left for 1 to 2 hrs under room temp. and room humidity after test.		
Terminal	Capacitance	Value must be stable during measurement.	Apply pressure to the device using the		
strength	Appearance	No noticeable irregularities.	specified tool for 5s so that the center deflection is 1mm (see below). $50 \xrightarrow{20} F (Units: mm) = F (Units: m$		

Tantalum capacitors

Ite	m	Performance	Test conditions		
Adhesion		Terminals must not detach.	With the device mounted on the printed circuit board, apply a force of 0.5 kg · f from each side for a period of 10 ± 1 s.		
External dimen	sions	Refer to "External dimensions"	Measure using slide calipers that meet the requirements of JIS B7507 Class 2.		
Markings	Resistance to solvents	Marking must be easy to read.	Immerse in isopropyl alcohol for $30 \pm 5s$.		
Solderability Inspect the solder cover of the terminals using a solder immersion test		At least 3 / 4 of the surface of the immersed terminals must be covered with new solder.	Immersion speed: 25 ± 2.5 mm / s Pre-processing (accelerated aging): leave for 1hr over boiling distilled water. Solder temperature: $235 \pm 5^{\circ}$ C Immersion time: 2 ± 0.5 s Solder type: H63A Flux: rosin 25%, IPA 75%		
Resistance to	Capacitance	Value must be stable during measurement.	Vibrate in the X / Y axis at frequencies o		
vibration	Appearance	No noticeable irregularities.	10~55~10Hz / minute for two hours each, with a total vibration amplitude of 1.5mm.		
Reverse polarity	Appearance	No noticeable irregularities, and the markings must be easy to read.	Apply either 0.1 times the rated voltage, or 3V, whichever is smaller, via a series		
withstanding voltage	L.C	Must be less than or equal to twice the initial specified value.	resister of 3Ω max. and 0.1Ω min. at a temperature of $85 \pm 2^{\circ}$ C.		
	ΔC / C	Within \pm 10% of the value before the test.			
	tanδ	Must be less than or equal to 1.5 times the initial specified value.			

Tantalum capacitors

•Table 1Standard list, TCFG series

Tantalum capacitors

						(P : 201	2 A:3216	B : 3528)
Part No.	Rated voltage at 85°C	Derated voltage at 125°C	Surge voltage at 85°C	Capacitance	Tolerance	Leakage current at 25°C 1WV.60s	DF 120Hz 25°C	Case code
	(V)	(V)	(V)	(μF)	(%)	(μA)	(%)	
TCF GP 0G 225□	4	2.5	5.2	2.2	±20,10	0.5	8	Р
TCF GP 0G 335□	4	2.5	5.2	3.3	±20,10	0.5	8	Р
TCF GP 0G 475□	4	2.5	5.2	4.7	±20,10	0.5	8	Р
TCF GA 0G 475□	4	2.5	5.2	4.7	±20,10	0.5	6	А
TCF GP 0G 685□	4	2.5	5.2	6.8	±20,10	0.5	10	Р
TCF GA 0G 685⊡	4	2.5	5.2	6.8	±20,10	0.5	6	А
TCF GP 0G 106□	4	2.5	5.2	10	±20,10	0.5	10	Р
TCF GA 0G 106□	4	2.5	5.2	10	±20,10	0.5	6	А
TCF GP 0G 156□	4	2.5	5.2	15	±20,10	0.6	10	Р
TCF GA 0G 156□	4	2.5	5.2	15	±20,10	0.6	6	А
TCF GB 0G 156□	4	2.5	5.2	15	±20,10	0.6	6	В
TCF GA 0G 226□	4	2.5	5.2	22	±20,10	0.9	6	А
TCF GB 0G 226□	4	2.5	5.2	22	±20,10	0.9	6	В
TCF GA 0G 336□	4	2.5	5.2	33	±20,10	1.3	8	А
TCF GB 0G 336□	4	2.5	5.2	33	±20,10	1.3	6	В
TCF GA 0G 476□	4	2.5	5.2	47	±20,10	1.9	8	А
TCF GB 0G 476□	4	2.5	5.2	47	±20,10	1.9	6	В
TCF GB 0G 686□	4	2.5	5.2	68	±20,10	2.7	8	В
TCF GB 0G 107□	4	2.5	5.2	100	±20,10	4.0	8	В
TCF GP 0J 155□	6.3	4	8	1.5	±20,10	0.5	8	Р
TCF GP 0J 225□	6.3	4	8	2.2	±20,10	0.5	8	Р
TCF GP 0J 335□	6.3	4	8	3.3	±20,10	0.5	8	Р
TCF GA 0J 335□	6.3	4	8	3.3	±20,10	0.5	6	А
TCF GP 0J 475□	6.3	4	8	4.7	±20,10	0.5	8	Р
TCF GA 0J 475□	6.3	4	8	4.7	±20,10	0.5	6	А
TCF GP 0J 685□	6.3	4	8	6.8	±20,10	0.5	10	Р
TCF GA 0J 685□	6.3	4	8	6.8	±20,10	0.5	6	А
TCF GP 0J 106□	6.3	4	8	10	±20,10	0.6	10	Р
TCF GA 0J 106□	6.3	4	8	10	±20,10	0.6	6	А
TCF GB 0J 106□	6.3	4	8	10	±20,10	0.6	6	В
TCF GA 0J 156□	6.3	4	8	15	±20,10	0.9	6	А
TCF GB 0J 156□	6.3	4	8	15	±20,10	0.9	6	В
TCF GA 0J 226□	6.3	4	8	22	±20,10	1.4	6	А
TCF GB 0J 226□	6.3	4	8	22	±20,10	1.4	6	В
TCF GA 0J 336□	6.3	4	8	33	±20,10	2.1	8	А
TCF GB 0J 336□	6.3	4	8	33	±20,10	2.1	6	В
TCF GB 0J 476□	6.3	4	8	47	±20,10	3.0	6	В
TCF GB 0J 686□	6.3	4	8	68	±20,10	4.3	8	В

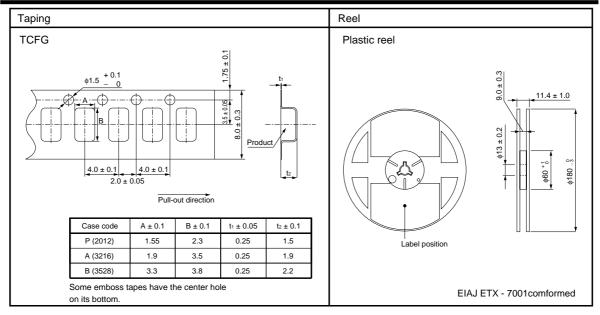
— Tolerance (M : ±20%, K : ±10%)

Tantalum capacitors

			-			(P : 2012	2 A:3216	B : 3528)
Part No.	Rated voltage at 85°C	Derated voltage at 125°C	Surge voltage at 85°C	Capacitance	Tolerance	Leakage current at 25°C 1WV.60s	DF 120Hz 25°C	Case code
	(V)	(V)	(V)	(μF)	(%)	(μA)	(%)	
TCF GP 1A 105 🗆	10	6.3	13	1.0	±20,10	0.5	8	Р
TCF GP 1A 155□	10	6.3	13	1.5	±20,10	0.5	8	Р
TCF GA 1A 155□	10	6.3	13	1.5	±20,10	0.5	6	A
TCF GP 1A 255□	10	6.3	13	2.2	±20,10	0.5	8	Р
TCF GA 1A 225□	10	6.3	13	2.2	±20,10	0.5	6	А
TCF GP 1A 335	10	6.3	13	3.3	±20,10	0.5	8	Р
TCF GA 1A 335	10	6.3	13	3.3	±20,10	0.5	6	А
TCF GP 1A 475	10	6.3	13	4.7	±20,10	0.5	8	Р
TCF GA 1A 475□	10	6.3	13	4.7	±20,10	0.5	6	А
TCF GB 1A 475	10	6.3	13	4.7	±20,10	0.5	6	В
TCF GA 1A 685□	10	6.3	13	6.8	±20,10	0.7	6	А
TCF GB 1A 685□	10	6.3	13	6.8	±20,10	0.7	6	В
TCF GA 1A 106□	10	6.3	13	10	±20,10	1.0	6	А
TCF GB 1A 106□	10	6.3	13	10	±20,10	1.0	6	В
TCF GA 1A 156□	10	6.3	13	15	±20,10	1.5	6	А
TCF GB 1A 156□	10	6.3	13	15	±20,10	1.5	6	В
TCF GB 1A 226□	10	6.3	13	22	±20,10	2.2	6	В
TCF GB 1A 336□	10	6.3	13	33	±20,10	3.3	6	В
TCF GB 1A 476□	10	6.3	13	47	±20,10	4.7	6	В
TCF GP 1C 105□	16	10	20	1.0	±20,10	0.5	8	Р
TCF GA 1C 105□	16	10	20	1.0	±20,10	0.5	4	А
TCF GA 1C 155□	16	10	20	1.5	±20,10	0.5	6	А
TCF GA 1C 225□	16	10	20	2.2	±20,10	0.5	6	А
TCF GA 1C 335	16	10	20	3.3	±20,10	0.5	6	А
TCF GB 1C 335□	16	10	20	3.3	±20,10	0.5	6	В
TCF GA 1C 475□	16	10	20	4.7	±20,10	0.8	6	А
TCF GB 1C 475□	16	10	20	4.7	±20,10	0.8	6	В
TCF GA 1C 685□	16	10	20	6.8	±20,10	1.1	6	А
TCF GB 1C 685□	16	10	20	6.8	±20,10	1.1	6	В
TCF GB 1C 106□	16	10	20	10	±20,10	1.6	6	В
TCF GB 1C 156□	16	10	20	15	±20,10	2.4	6	В
TCF GB 1C 226□	16	10	20	22	±20,10	3.5	6	В
TCF GA 1D 105□	20	13	26	1.0	±20,10	0.5	4	А

- Tolerance (M : ±20%, K : ±10%)

Tantalum capacitors



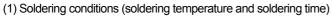
Packaging style

Part No.	Package type	Packaging style		Symbol	Basic ordering unit (pcs)
TCFG	Taping	Plastic taping	φ180 mm reel	R	2,000

70

Tantalum capacitors

• Electrical characteristics and operation notes



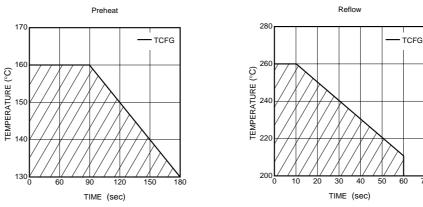
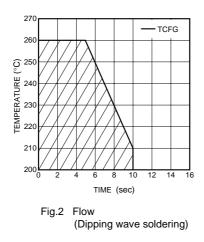
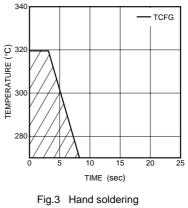
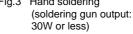


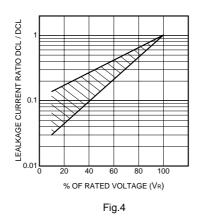
Fig.1 Reflow (Infrared Ray, Hot Plate, Hot Air)



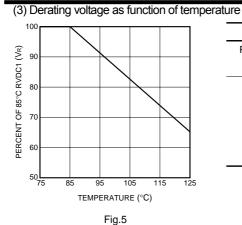




(2) Leakage current-to-voltage ratio



Tantalum capacitors



85	5°C	125°C		
Rated Voltage	Surge Voltage	Category Voltage	Surge Voltage	
(V.DC)	(V.DC)	(V.DC)	(V.DC)	
4	5.2	2.5	3.4	
6.3	8	4	5	
10	13	6.3	9	
16	20	10	12	
20	26	13	16	

(4) Reliability

The malfunction rate of tantalum solid state electrolytic capacitors varies considerably depending on the conditions of usage (ambient temperature, applied voltage, circuit resistance).

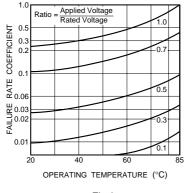
Formula for calculating malfunction rate

 $\lambda p = \lambda b \times (\pi E \times \pi SR \times \pi Q \times \pi CV)$

- λp : Malfunction rate stemming from operation
- λb : Basic malfunction rate
- π_{E} : Environmental factors
- π_{SR} : Series resistance
- π_Q : Level of malfunction rate
- π_{CV} : Capacitance

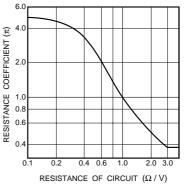
For details on how to calculate the malfunction rate stemming from operation, see the tantalum solid state electrolytic capacitors column in MIL-HDBK-217.

Malfunction rate as function of operating temperature and rated voltage





Malfunction rate as function of circuit resistance (Ω /V)







(5) External temperature vs. fuse blowout (6) Power vs. fuse blowout characteristics / Product surface temperature 100 36 ---- P case (2012) ---- A case (3216) ô case (2012) 90 (C) 350 340 330 330 310 310 300 290 280 case (3216 THE PRODUCT B case (3528 В case (3528 80 າບປ OPERATING TIME (sec) Open-function charcteristic 70 60 F the product curve of 50 . ЧО 40 00 TEMP. 30 ailed SURFACE ' 20 150 area 27 1(0 0 260 10 No operating area ELECTRIC POWER (W) TIME (sec) Fig.9 Fig.8

Note: Solder the chip at 300°C or less. If it is soldered using a temperature higher than 300°C, open function built-in may operate.

(7) Maximum power dissipation

Tantalum capacitors

Warming of the capacitor due to ripple voltage balances with warming caused by Joule heating and by radiated heat. Maximum allowable warming of the capacitor is to 5°C above ambient temperature. When warming exceeds 5°C, it can damage the dielectric and cause a short circuit.

Power dissipation (P) = $I^2 \cdot R$

Ripple current

P: As shown in table at right

R : Equivalent series resistance

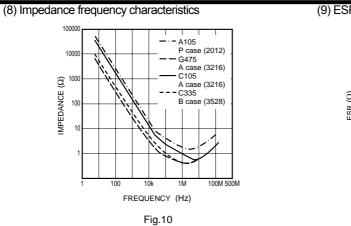
Notes:

1. Please be aware that when case size is changed, maximum allowable power dissipation is reduced.

2. Maximum power dissipation varies depending on the package. Be sure to use a case which will keep warming within the limits shown in the table below.

Ambient temp. Case	+25°C	+55°C	+85°C	+125°C
P case (2012)	0.025	0.022	0.020	0.010
A case (3216)	0.070	0.063	0.056	0.028
B case (3528)	0.080	0.072	0.064	0.032
Max. temp. rise	5	5	5	2

Allowable power dissipation (W) and maximum temperature rising



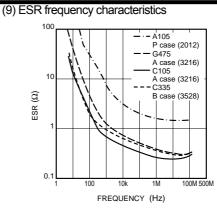
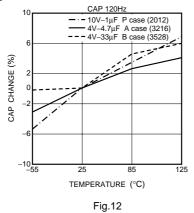
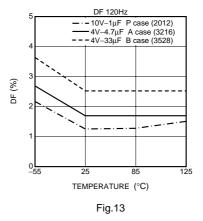


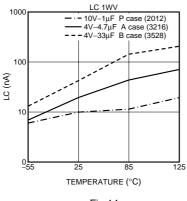
Fig.11

(10) Temperature characteristics

Tantalum capacitors







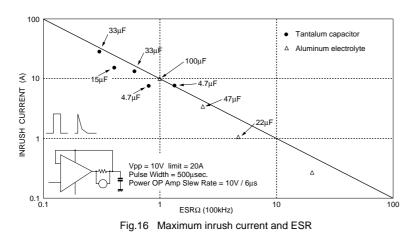


Tantalum capacitors

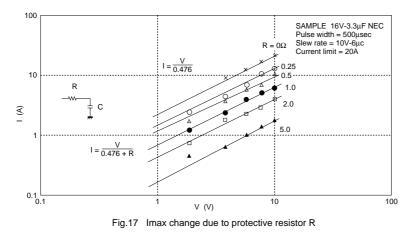
Inrush current

Beware of inrush current.

Inrush currents are inversely proportional to ESR. Large inrush currents can cause component failure.



Inrush current can be limited by means of a protective resistor.



(11) Ultrasonic cleaning

Carry out cleaning under the mildest conditions possible. The internal element of a tantalum capacitor are larger than those of a transistor or diode, so it is not as resistant to ultrasonic waves.

Example : water Propagation speed 1500m / s Solvent density 1g / cm³

Frequency and wavelength					
Frequency	Wavelength				
20kHz	7.5cm				
28kHz	5.3cm				
50kHz	3.0cm				

Precautions

Tantalum capacitors

- 1) Do not allow solvent to come to a boil (kinetic energy increases).
 - Ultrasonic output $0.5W / cm^2$ or less
 - · Use a solvent with a high boiling point.
- · Lower solvent temperature.
- 2) Ultrasonic cleaning frequency
- 28 kHz or less
- 3) Keep cleaning time as short as possible.

4) Move item being cleaned.
Standing waves caused by the ultrasonic waves can cause stress to build up in part of the item being cleaned.

Reference

Kinetic energy = 2 x π x frequency x $\sqrt{\frac{2 \text{ x ultrasonic output}}{\text{propagation speed x solvent density}}}$



Appendix

Notes

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